

LSIC2SD065D10A 650 V, 10 A SiC Schottky Barrier Diode











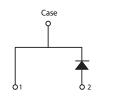
Description

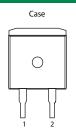
This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- AEC-Q101 qualified
- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- · Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

Circuit Diagram TO-263-2L





Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- · Solar inverters
- Industrial motor drives
- EV charging stations

Environmental

- Littelfuse "RoHS" logo = RoHS RoHS conform
- Littelfuse "HF" logo = HF Halogen Free
- Littelfuse "Pb-free" logo = Po Pb-free lead plating

Maximum Ratings

Characteristics	Symbol	Conditions	Value	Unit	
Repetitive Peak Reverse Voltage	V _{RRM}	-	650	V	
DC Blocking Voltage	V _R	T _J = 25 °C	650	V	
Continuous Forward Current		T _C = 25 °C	27	А	
	l _F	T _C = 135 °C	12.5		
		T _C = 147 °C	10		
Non-Repetitive Forward Surge Current	I _{FSM}	$T_{\rm C} = 25 {\rm ^{\circ}C}$, $T_{\rm P} = 10 {\rm ms}$, Half sine pulse	48	А	
Power Dissipation	P _{Tot}	T _c = 25 °C	100	W	
		T _C = 110 °C	43		
Operating Junction Temperature	T _J	-	-55 to 175	°C	
Storage Temperature	T _{STG}	-	-55 to 150	°C	
Soldering Temperature	T _{SOLD}	-	260	°C	

Electrical Characteristics (T, = 25 °C unless otherwise specified)

	Symbol	Conditions	Value				
Characteristics			Min.	Тур.	Max.	Unit	
Forward Voltage	\/	I _F = 10 A, T _J = 25 °C	-	1.5	1.8	V	
	V _F	I _F = 10 A, T _J = 175 °C	-	1.85	-		
Reverse Current	I _R	$V_{R} = 650 \text{V}$, $T_{J} = 25 ^{\circ}\text{C}$	-	<1	50	μА	
		$V_{R} = 650 \text{ V}, T_{J} = 175 ^{\circ}\text{C}$	-	25	-		
Total Capacitance		V _R = 1 V, f = 1 MHz	-	470	-		
	С	$V_{R} = 200 V, f = 1 MHz$	-	60	-	pF	
		V _R = 400 V, f = 1 MHz	-	43	-		
Total Capacitive Charge	O _c	$V_R = 400 \text{ V}, Q_C = \int\limits_0^V C(V) dV$	-	30	-	nC	

Thermal Characteristics				
Characteristics	Symbol	Value	Unit	
Thermal Resistance	R _{euc}	1.5	°C/W	

Figure 1: Typical Foward Characteristics

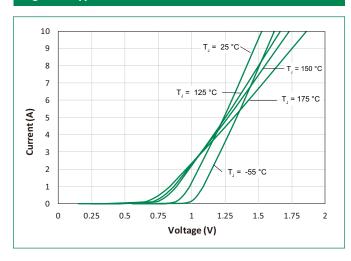


Figure 2: Typical Reverse Characteristics

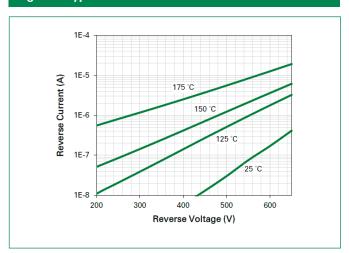




Figure 3: Power Derating

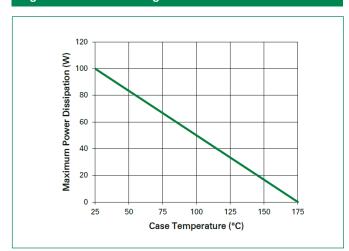


Figure 4: Current Derating

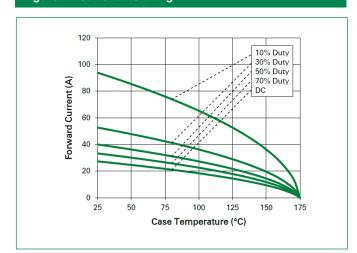


Figure 5: Capacitance vs. Reverse Voltage

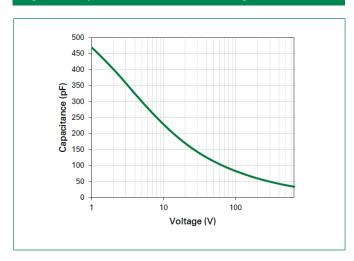


Figure 6: Capacitive Charge vs. Reverse Voltage

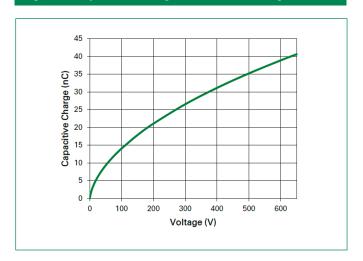


Figure 7: Stored Energy vs. Reverse Voltage

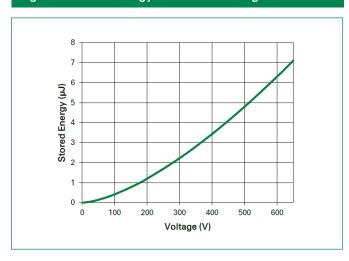
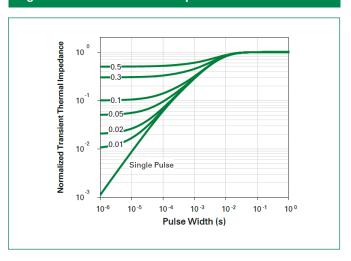
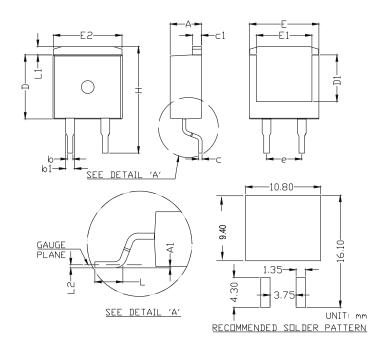


Figure 8: Transient Thermal Impedance



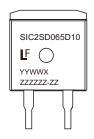
Dimensions-Package TO-263-2L



Cumbal	Millimeters				
Symbol	Min	Nom	Max		
А	4.30	4.50	4.70		
A1	0.00	-	0.25		
b	0.70	0.80	0.90		
b1	1.17	1.27	1.37		
С	0.46	0.50	0.60		
c1	1.25	1.30	1.40		
D	9.00	9.20	9.40		
D1	6.50	6.70	6.90		
Е	9.80	10.00	10.20		
E1	7.80	8.00	8.20		
E2	9.70	9.90	10.10		
е	5.08 BSC				
Н	15.00	15.30	15.60		
L	2.00	2.30	2.60		
L1	1.00	1.20	1.40		
L2	0.254 BSC				

Part Numbering and Marking System

SD



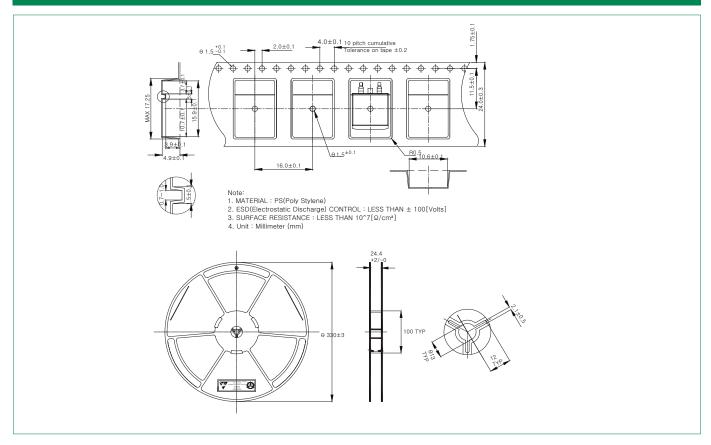
- SIC = SiC Diode 2 = Gen2
 - = Genz = Schottky Diode
- 065 = Voltage Rating (650 V) D = TO-263-2L (D2PAK)
- 10 = 10-263-2L (D2PAK) 10 = Current Rating (10 A)
- YY = Year WW = Week X = Special Code
- ZZZZZZ-ZZ = Lot Number

Packing Option

Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD065D10A	SIC2SD065D10	Tape and Reel	800



TO-263 Carrier Reel Specifications



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